# NSN 5961-01-009-4959

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-009-4959

Inclosure Material:

Ceramic

**Overall Length:** 

0.128 inches

#### **Overall Diameter:**

0.230 inches

#### **End Application:**

Airport surveillance radar 8 (asr8)

#### **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

# Thread Size:

0.140 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

50.0 collector to base voltage/static/emitter open

#### **Current Rating Per Characteristic:**

120.00 milliamperes all primaries

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unc

### Terminal Type And Quantity:

4 ferrule

#### Shelf Life:

N/a

## Unit Of Measure:

---

#### Demilitarization:

Yes - demil/mli

#### Fiig:

A110a0